



# **High-Quality Sound, J-FET Input, Single Operational Amplifier for Premium Audio**

#### **■FEATURES**

High-quality sound

 Operating Voltage Operating Current

Low Input Bias Current

Low Noise

Ultralow Distortion

High Slew Rate

Gain Bandwidth Product

J-FET Input

Package Outline

±3.5V to ±18V 5.8mA typ.

5pA typ.

7.5nV/√Hz typ. at f=1kHz 0.00003% typ. at f=1kHz

35V/µs typ.

12MHz typ.

DIP8 (OFC lead-frame) OFC: Oxygen-Free Copper

#### **■GENERAL DESCRIPTION**

The MUSES03 is a high-quality sound J-FET input single operational amplifier for premium audio equipment.

The MUSES03 uses advanced circuit design and special material and assembly technology to high-quality sound.

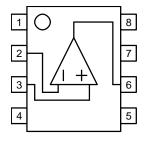
The MUSES03 features high-quality sound, low input bias current, low noise, ultralow distortion and high slew rate, and it is suitable for I/V converters, preamplifiers, active filters, headphone amplifiers, and line amplifiers.

#### **■APPLICATION**

- Hi-Fi Audio Application
- Professional Audio Application

## **■PIN CONFIGURATION**

PIN NO.	SYMBOL
1	NC
2	-INPUT
3	+INPUT
4	V-
5	NC
6	OUTPUT
7	V+
8	NC



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# **■ORDERING INFORMATION**

PART NUMBER	PACKAGE OUTLINE	RoHS	HALOGEN- FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ(pcs)
MUSES03	DIP8	yes	yes	Sn-2Bi	03	470	200

Note: "-" is non-evaluation. Please contact your sales representative for more information.

# **■ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V*- V	±19	V
Differential Input Voltage	V <sub>ID</sub>	±6	V
Input Voltage	V <sub>IN</sub>	±18 <sup>(1)</sup>	V
Output Peak Current	I <sub>OP</sub>	250	mA
Power Dissipation (Ta=25°C)	$P_{D}$	870 <sup>(2)</sup>	mW
Operating Temperature Range	T <sub>opr</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-50 to+150	°C

<sup>(1):</sup> If the supply voltage is less than  $\pm 18V$ , the input voltage must not over the supply voltage.

# **■RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V <sup>+</sup> - V <sup>-</sup>	±3.5 to ±18	V

<sup>(2):</sup> Mounted on glass epoxy board. (76.2×114.3×1.6mm: based on EIA/JDEC standard, 2Layers)



#### **■POWER DISSIPATION vs. AMBIENT TEMPERATURE**

IC is heated by own operation and possibly gets damage when the junction power exceeds the acceptable value called Power Dissipation  $P_D$ . The dependence of the MUSES03  $P_D$  on ambient temperature is shown in Fig 1. The plots are depended on following two points. The first is  $P_D$  on ambient temperature 25°C, which is the maximum power dissipation. The second is 0W, which means that the IC cannot radiate any more. Conforming the maximum junction temperature Tjmax to the storage temperature Tstg derives this point. Fig.1 is drawn by connecting those points and conforming the  $P_D$  lower than 25°C to it on 25°C. The  $P_D$  is shown following formula as a function of the ambient temperature between those points.

Dissipation Power 
$$P_D = \frac{Tjmax - Ta}{\theta ja}$$
 [W] (Ta  $\geq$  25°C)

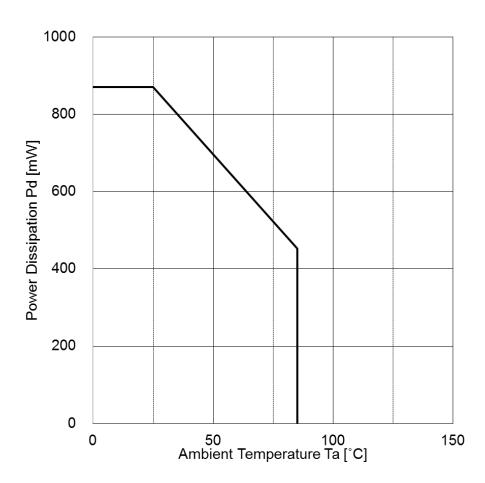
Where,  $\theta$  is heat thermal resistance which depends on parameters such as package material, frame material and so on. Therefore,  $P_D$  is different in each package.

While, the actual measurement of dissipation power on MUSES03 is obtained using following equation.

(Actual Dissipation Power) = (Supply Current Icc) X (Supply Voltage V<sup>+</sup>– V-) – (Output Power Po)

The MUSES03 should be operated in lower than P<sub>D</sub> of the actual dissipation power.

To sustain the steady state operation, take account of the Dissipation Power and thermal design.





# **■ELECTRICAL CHARACTERISTICS** (Ta=25 °C)

DC CHARACTERISTICS (V<sup>+</sup>/V=±15V, R<sub>L</sub> to GND, Ta=25°C, unless otherwise specified)

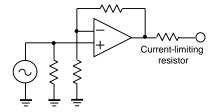
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	Icc	No Signal, R <sub>L</sub> =∞	-	5.8	10	mA
Input Offset Voltage	V <sub>IO</sub>	R <sub>S</sub> =50Ω	-	1.0	-	mV
Input Bias Current	I <sub>B</sub>		-	5.0	250	pА
Input Offset Current	I <sub>IO</sub>		-	2.0	220	pА
Voltage Gain 1	A <sub>V1</sub>	$R_L$ =10k $\Omega$ , Vo=±13V	90	115	-	dB
Voltage Gain 2	A <sub>V2</sub>	R <sub>L</sub> =2kΩ, Vo=±12.8V	90	115	-	dB
Voltage Gain 3	A <sub>V3</sub>	R <sub>L</sub> =600Ω, Vo=±12.5V	90	115	-	dB
Common Mode Rejection Ratio	CMR	V <sub>ICM</sub> =±12.5V	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	V <sup>+</sup> /√=±3.5 to ±18V	80	100	-	dB
Max Output Voltage 1	V <sub>OM1</sub>	$R_L$ =10k $\Omega$	±13.0	±14.0	-	V
Max Output Voltage 2	V <sub>OM2</sub>	R <sub>L</sub> =2kΩ	±12.8	±13.8	-	V
Max Output Voltage 3	V <sub>OM2</sub>	R <sub>L</sub> =600Ω	±12.5	±13.5	-	V
Input Common Mode Voltage Range	V <sub>ICM</sub>	CMR≥70dB	±12.0	±13.0	-	V

AC CHARACTERISTICS (V<sup>+</sup>/V=±15V, VcM=0V, Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gain Bandwidth Product	GB	f=10kHz	-	12	-	MHz
Unity Gain Frequency	f <sub>T</sub>	$A_V$ =+100, $R_S$ =100 $\Omega$ , $R_L$ =2 $k\Omega$ , $C_L$ =10 $pF$	-	13	1	MHz
Phase Margin	$\Phi_{M}$	$A_V$ =+100, $R_S$ =100 $\Omega$ , $R_L$ =2k $\Omega$ , $C_L$ =10pF	ı	70	ı	Deg
Input Noise Voltage1	$V_{NI1}$	f=1kHz	-	7.5	1	nV/√Hz
Input Noise Voltage2	$V_{NI2}$	f=20-20kHz	-	1.0	-	μVrms
Total Harmonic Distortion	THD	$f=1kHz$ , $A_V=+10$ , $Vo=5Vrms$ , $R_L=2k\Omega$	ı	0.00003	1	%
Slew Rate	SR	$A_V=1, V_{IN}=2Vp-p, R_L=2k\Omega, C_L=10pF$	-	35	ı	V/us

## ■ NOTE

The output current should not exceed the maximum output peak current (250mA) of absolute maximum ratings. If the maximum output peak current exceeds 250mA, connect a current-limiting resistor to the output.



Calculating formula: R= V/I

 $R(\Omega)$ : Current-limiting resistor

V(V): Supply voltage I (A): Output peak current

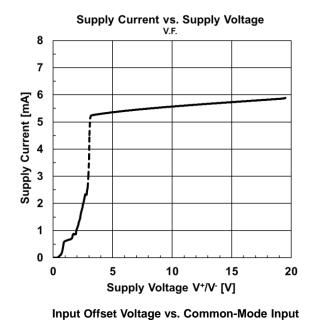
Example

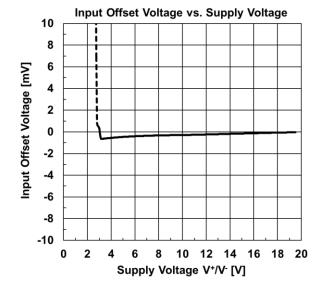
18V/  $\dot{0}$ .2A=90Ω or more (91Ω, 100Ω) 9V/ 0.2A=45Ω or more (47Ω, 51Ω)

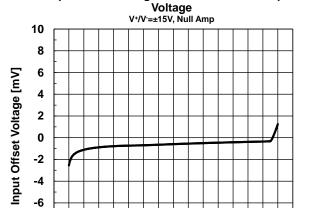
Resistance value is a reference value. It does not guarantee the characteristics of the product.



## **■ TYPICAL CHARACTERISTICS**

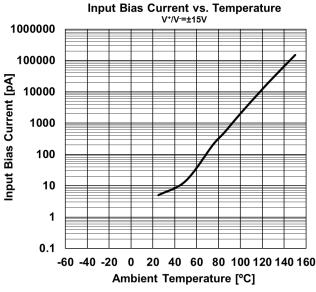


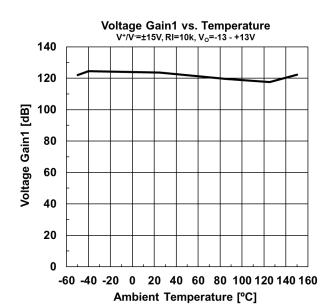


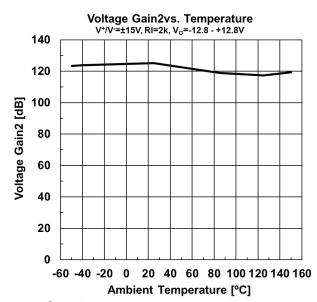


-16-14-12-10-8 -6 -4 -2 0 2 4 6 8 10 12 14 16

Common-Mode Input Voltage [V]



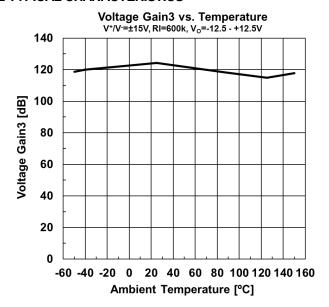


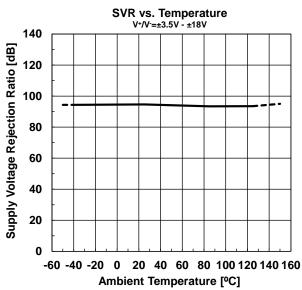


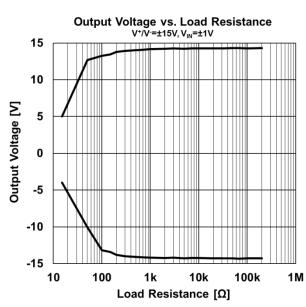
-8 -10

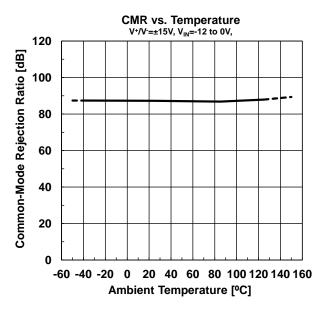


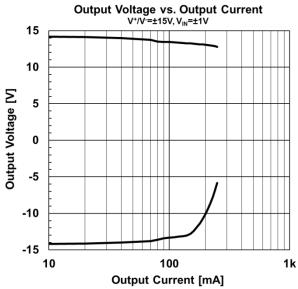
#### **■ TYPICAL CHARACTERISTICS**

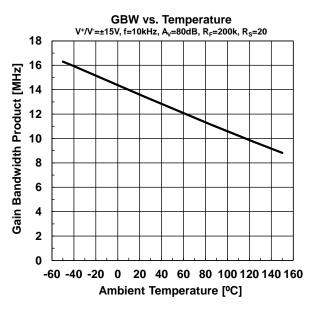






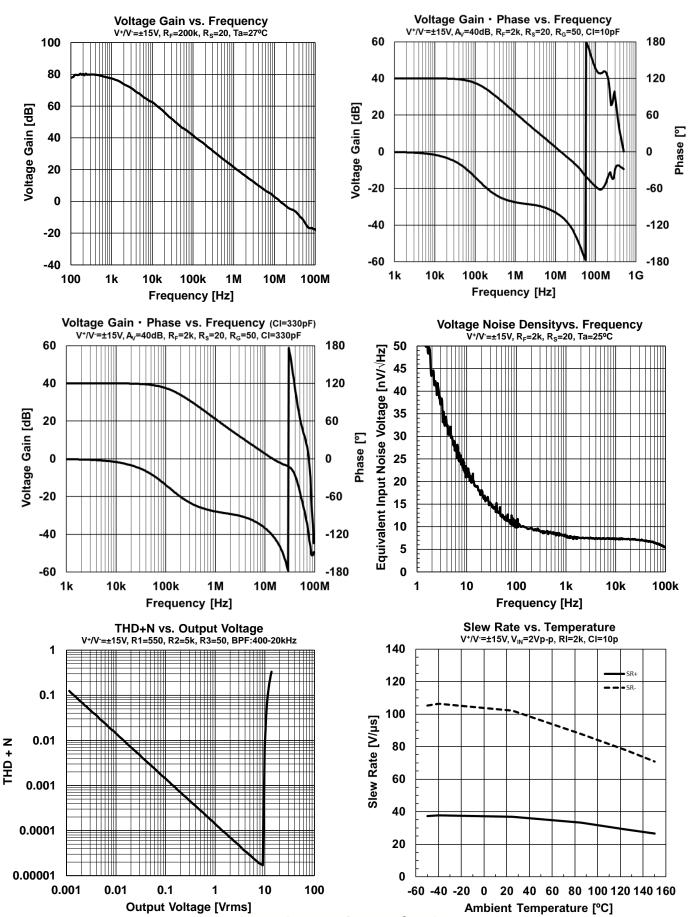








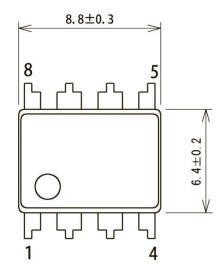
#### **■ TYPICAL CHARACTERISTICS**

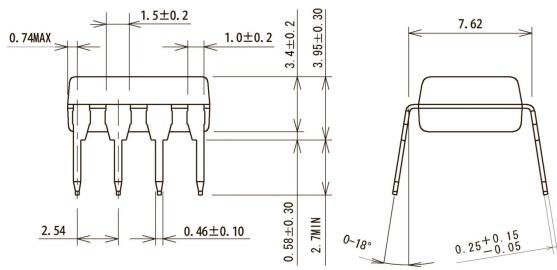




# **■PACKAGE OUTLINE**

DIP8(MUSES)







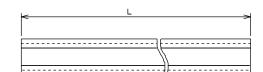
# **■PACKING SPECIFICATION**

Plastic Tube Container Dimensions

DIP8(MUSES) packages are packed in the plastic tube container. The dimensions are mentioned as follows.

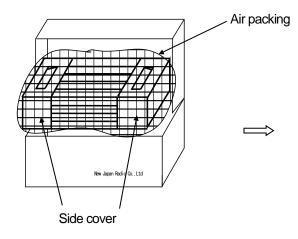
# Plastic Tube Container dimensions for DIP8(MUSES)

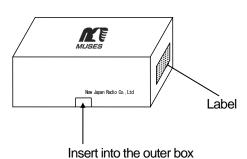
Symbol	DIP8
	(Carbon tube)
Н	10.6mm
L	110mm
W	13.2mm
Material	PS Carbon
Stopper	Rubber Knob
Contents	10pcs





# Put in the outer box



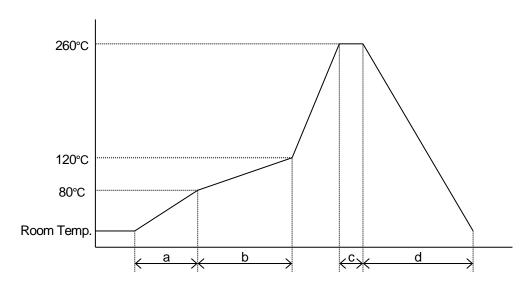




## **■RECOMMENDED MOUNTING METHOD**

#### FLOW SOLDERING METHOD

## \* flow soldering procedure



a:Temperature ramping rate : 1 to 7°C /s b:Pre-heating temperature : 80 to 120°C Pre-heating time : 60 to 120s

c:Peak temperature : not exceeding 260°C

Peak time : within 10s d:Temperature ramping rate : 1 to 7°C/s

The temperature indicates at the surface of mold package.

## IRON SOLDERING METHOD

\* Iron Soldering conditions
Temperature of Iron: not exceeding 350°C
Soldering time: within 3s ( At 1 lead)

#### **■PRECAUTION FOR COUNTERFEIT SEMICONDUCTOR PRODUCTS**

We have recently detected many counterfeit semiconductor products that have very similar appearances to our operational amplifier "MUSES" in the world-wide market. In most cases, it is hard to distinguish them from our regular products by their appearance, and some of them have very poor quality and performance.

They can not provide equivalent quality of our regular product, and they may cause breakdowns or malfunctions if used in yoursystems or applications.

We would like our customers to purchase "MUSES" through our official sales channels : our sales branches, sales subsidiaries and distributors.

Please note that we hold no responsibilities for any malfunctions or damages caused by using counterfeit products. We would appreciate your understanding.



## [CAUTION]

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Various Safety devices

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